

---

# HA17339/A Series

## Quadruple Comparators

# HITACHI

ADE-204-065A (Z)

Rev. 1

Mar. 2001

---

### Description

The HA17339A and HA17339 series products are comparators designed for general purpose, especially for power control systems.

These ICs operate from a single power-supply voltage over a wide range of voltages, and feature a reduced power-supply current since the supply current is independent of the supply voltage.

These comparators have the merit which ground is included in the common-mode input voltage range at a single-voltage power supply operation. These products have a wide range of applications, including limit comparators, simple A/D converters, pulse/square-wave/time delay generators, wide range VCO circuits, MOS clock timers, multivibrators, and high-voltage logic gates.

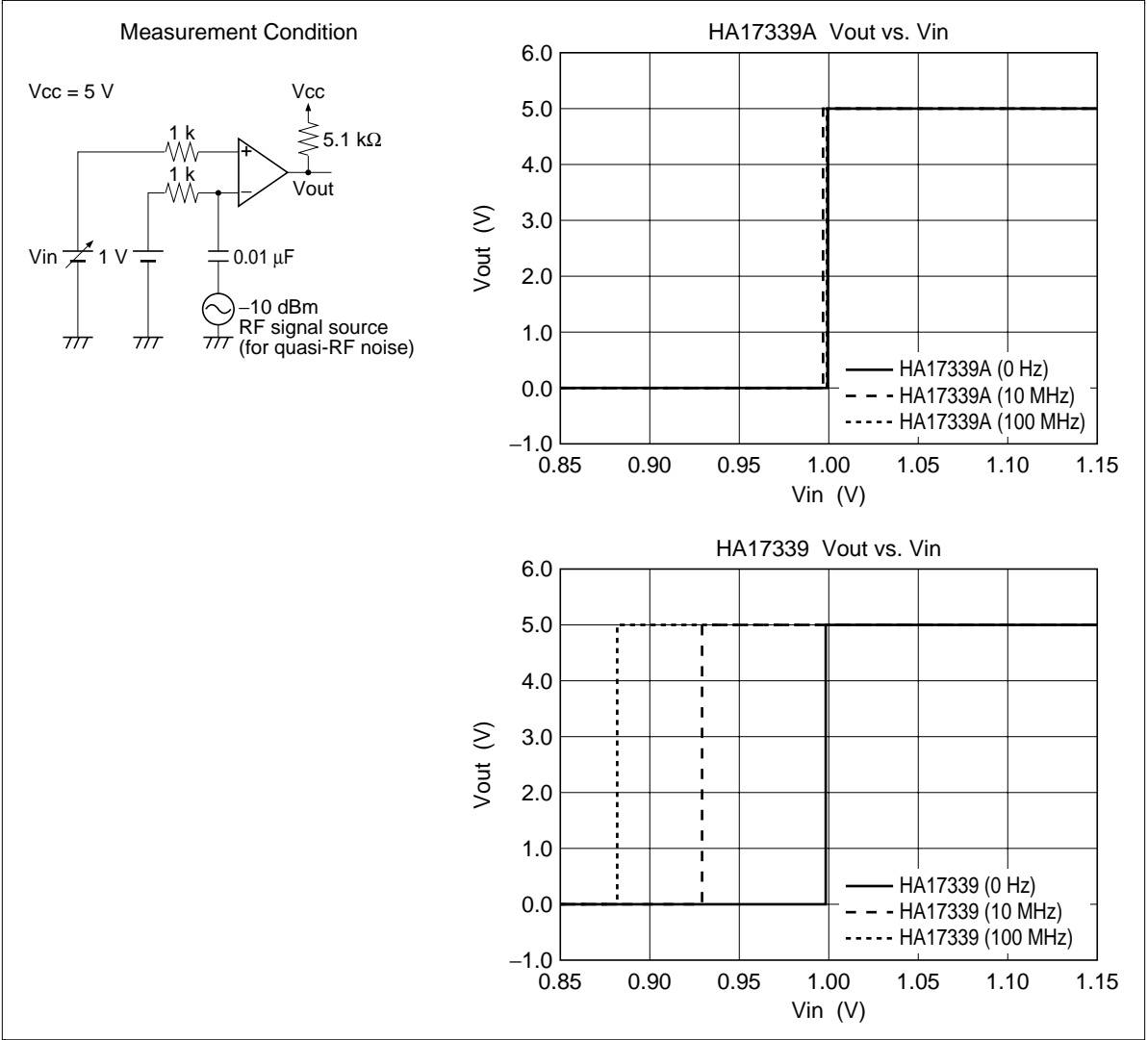
### Features

- Wide power-supply voltage range: 2 to 36 V
- Very low supply current: 0.8 mA
- Low input bias current: 25 nA
- Low input offset current: 5 nA
- Low input offset voltage: 2 mV
- The common-mode input voltage range includes ground.
- Low output saturation voltage: 1 mV (5  $\mu$ A), 70 mV (1 mA)
- Output voltages compatible with CMOS logic systems

# HA17339/A Series

## Features only for “A” series

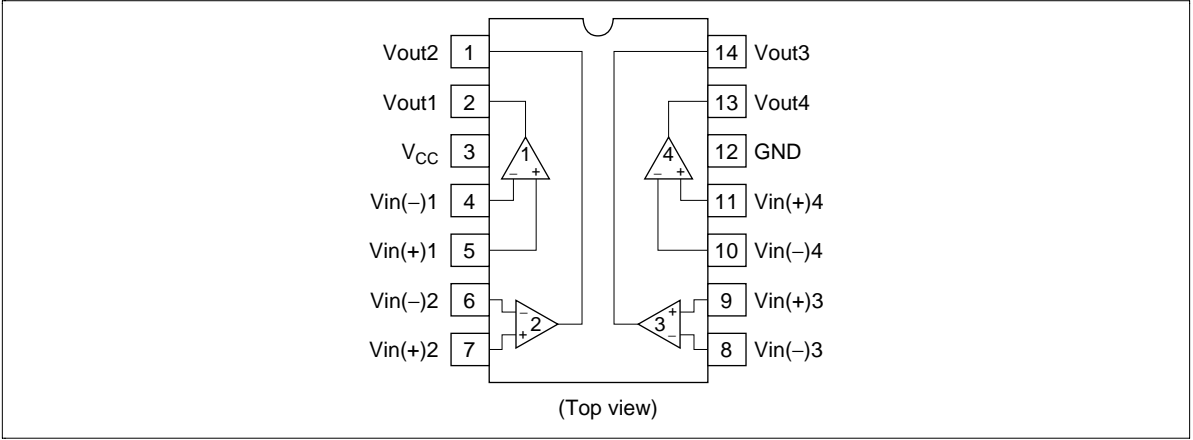
- Low electro-magnetic susceptibility



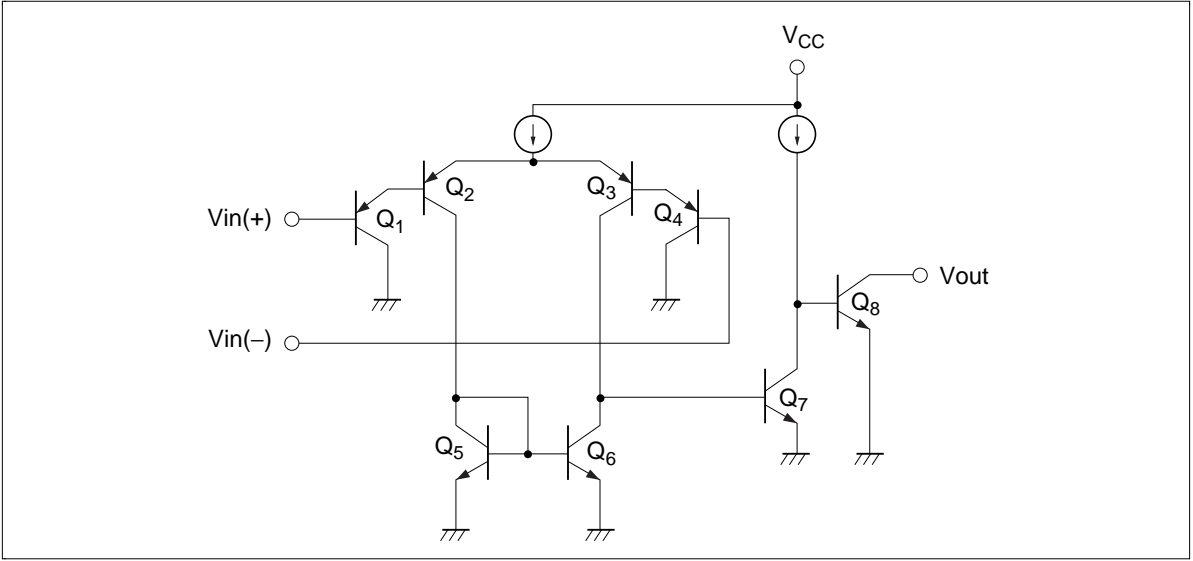
## Ordering Information

Type No.	Application	Package
HA17339AP	Industrial use	DP-14
HA17339ARP	Commercial use	FP-14DN
HA17339AFP		FP-14DA
HA17339	Commercial use	DP-14
HA17339F		FP-14DA

Pin Arrangement



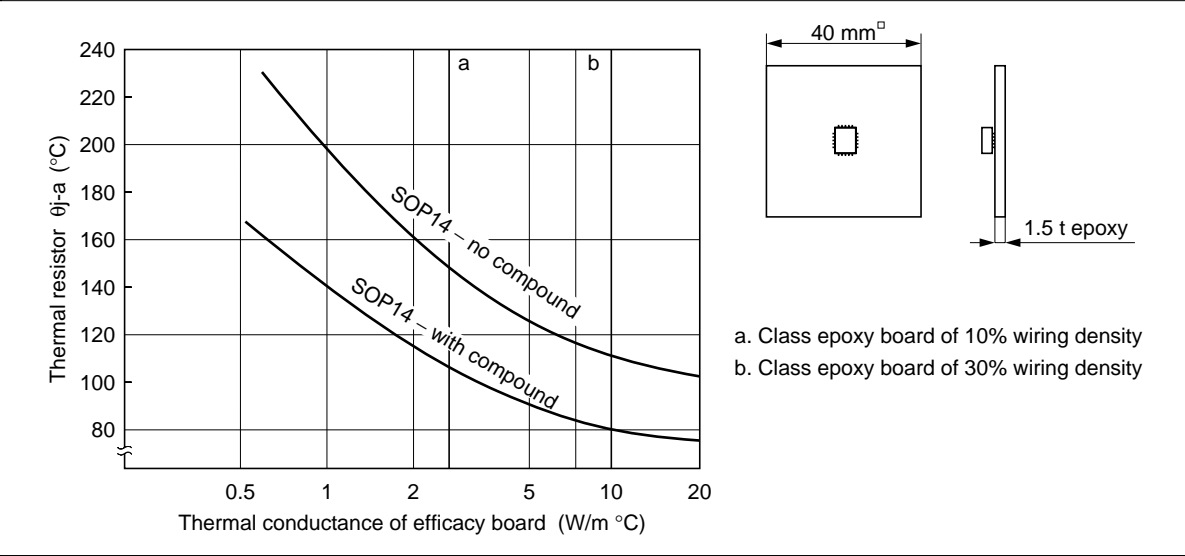
Circuit Structure (1/4)



Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings					Unit
		17339AP	17339AFP	17339ARP	17339	17339F	
Power supply voltage	V <sub>CC</sub>	36	36	36	36	36	V
Differential input voltage	V <sub>in(diff)</sub>	±V <sub>CC</sub>	±V <sub>CC</sub>	±V <sub>CC</sub>	±V <sub>CC</sub>	±V <sub>CC</sub>	V
Input voltage	V <sub>in</sub>	−0.3 to +V <sub>CC</sub>	−0.3 to +V <sub>CC</sub>	−0.3 to +V <sub>CC</sub>	−0.3 to +V <sub>CC</sub>	−0.3 to +V <sub>CC</sub>	V
Output current	I <sub>out</sub> *2	20	20	20	20	20	mA
Allowable power dissipation	P <sub>T</sub>	625 *1	625 *3	625 *3	625 *1	625 *3	mW
Operating temperature	T <sub>opr</sub>	−40 to +85	−40 to +85	−40 to +85	−20 to +75	−20 to +75	°C
Storage temperature	T <sub>stg</sub>	−55 to +125	−55 to +125	−55 to +125	−55 to +125	−55 to +125	°C
Output pin voltage	V <sub>out</sub>	36	36	36	36	36	V

Notes: 1. These are the allowable values up to Ta = 50°C. Derate by 8.3 mW/°C above that temperature.  
2. These products can be destroyed if the output and V<sub>CC</sub> are shorted together. The maximum output current is the allowable value for continuous operation.  
3. T<sub>jmax</sub> = θ<sub>j-a</sub> · P<sub>C</sub>max + Ta (θ<sub>j-a</sub>; Thermal resistor between junction and ambient at set board use).  
The wiring density and the material of the set board must be chosen for thermal conductance of efficacy board.  
And P<sub>C</sub>max cannot be over the value of P<sub>T</sub>.



**Electrical Characteristics** ( $V_{CC} = 5\text{ V}$ ,  $T_a = 25^\circ\text{C}$ )

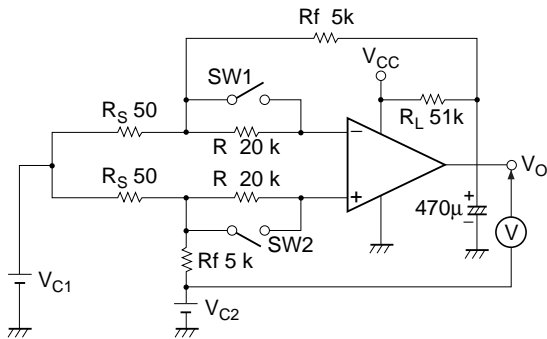
Item	Symbol	Min	Typ	Max	Unit	Test Condition
Input offset voltage	$V_{IO}$	—	2	7	mV	Output switching point: when $V_O = 1.4\text{ V}$ , $R_S = 0\Omega$
Input bias current	$I_{IB}$	—	25	250	nA	$I_{IN(+)}$ or $I_{IN(-)}$
Input offset current	$I_{IO}$	—	5	50	nA	$I_{IN(+)} - I_{IN(-)}$
Common-mode input voltage <sup>*1</sup>	$V_{CM}$	0	—	$V_{CC} - 1.5$	V	
Supply current	$I_{CC}$	—	0.8	2	mA	$R_L = \infty$
Voltage Gain	$A_V$	—	200	—	V/mV	$R_L = 15\text{k}\Omega$
Response time <sup>*2</sup>	$t_R$	—	1.3	—	$\mu\text{s}$	$V_{RL} = 5\text{ V}$ , $R_L = 5.1\text{k}\Omega$
Output sink current	$I_{osink}$	6	16	—	mA	$V_{IN(-)} = 1\text{ V}$ , $V_{IN(+)} = 0$ , $V_O \leq 1.5\text{ V}$
Output saturation voltage	$V_O \text{ sat}$	—	200	400	mV	$V_{IN(-)} = 1\text{ V}$ , $V_{IN(+)} = 0$ , $I_{osink} = 3\text{ mA}$
Output leakage current	$I_{LO}$	—	0.1	—	nA	$V_{IN(+)} = 1\text{ V}$ , $V_{IN(-)} = 0$ , $V_O = 5\text{ V}$

Notes: 1. Voltages more negative than  $-0.3\text{ V}$  are not allowed for the common-mode input voltage or for either one of the input signal voltages.

2. The stipulated response time is the value for a  $100\text{ mV}$  input step voltage that has a  $5\text{ mV}$  overdrive.

Test Circuits

1. Input offset voltage ( $V_{IO}$ ), input offset current ( $I_{IO}$ ), and Input bias current ( $I_{IB}$ ) test circuit



SW1	SW2	Vout
On	On	$V_{O1}$
Off	Off	$V_{O2}$
On	Off	$V_{O3}$
Off	On	$V_{O4}$

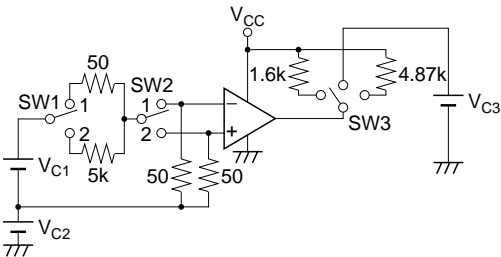
$V_{C1} = \frac{1}{2} V_{CC}$   
 $V_{C2} = 1.4V$

$V_{IO} = \frac{|V_{O1}|}{1 + R_f / R_S}$  (mV)

$I_{IO} = \frac{|V_{O2} - V_{O1}|}{R(1 + R_f / R_S)}$  (nA)

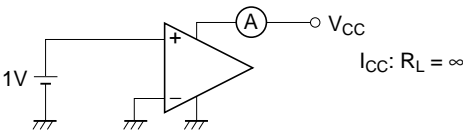
$I_{IB} = \frac{|V_{O4} - V_{O3}|}{2 \cdot R(1 + R_f / R_S)}$  (nA)

2. Output saturation voltage ( $V_{O sat}$ ) output sink current ( $I_{osink}$ ), and common-mode input voltage ( $V_{CM}$ ) test circuit

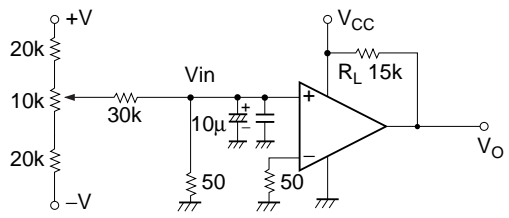


Item	$V_{C1}$	$V_{C2}$	$V_{C3}$	SW1	SW2	SW3	Unit
$V_{O sat}$	2V	0V	—	1	1	1 at $V_{CC} = 5V$ 3 at $V_{CC} = 15V$	V
$I_{osink}$	2V	0V	1.5V	1	1	2	mA
$V_{CM}$	2V	-1 to $V_{CC}$	—	2	Switched between 1 and 2	3	V

3. Supply current ( $I_{CC}$ ) test circuit

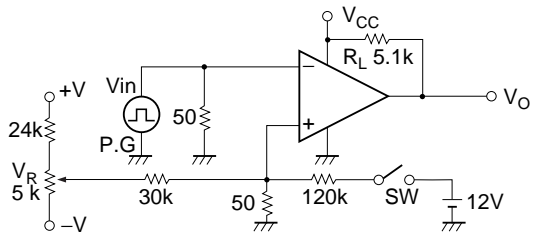


4. Voltage gain ( $A_V$ ) test circuit ( $R_L = 15k\Omega$ )



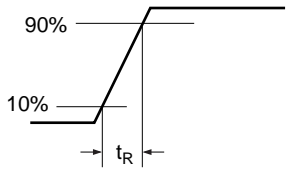
$$A_V = 20 \log \frac{V_{O1} - V_{O2}}{V_{IN1} - V_{IN2}} \quad (\text{dB})$$

5. Response time ( $t_R$ ) test circuit



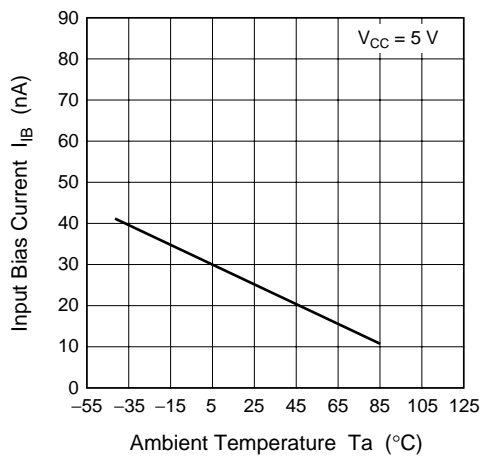
$t_R$ :  $R_L = 5.1k\Omega$ , a 100mV input step voltage that has a 5mV overdrive

- With  $V_{IN}$  not applied, set the switch SW to the off position and adjust  $V_R$  so that  $V_O$  is in the vicinity of 1.4V.
- Apply  $V_{IN}$  and turn the switch SW on.

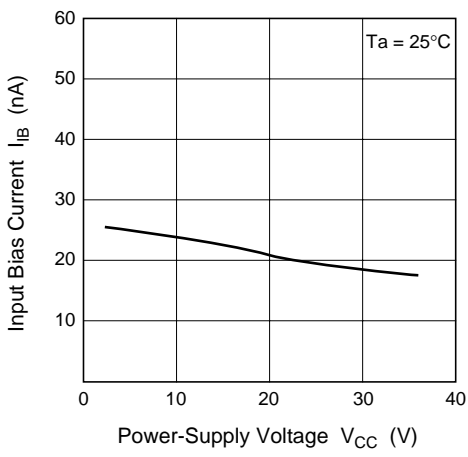


Characteristic Curves

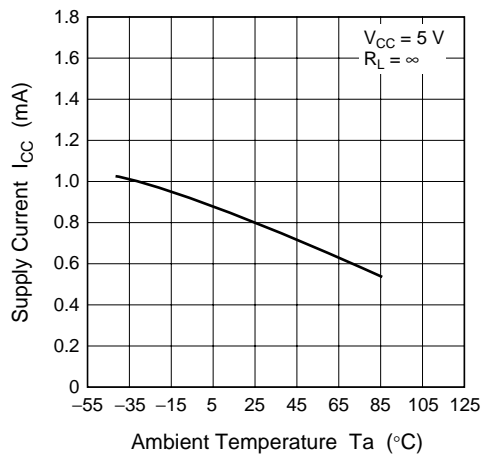
Input Bias Current vs.  
Ambient Temperature Characteristics



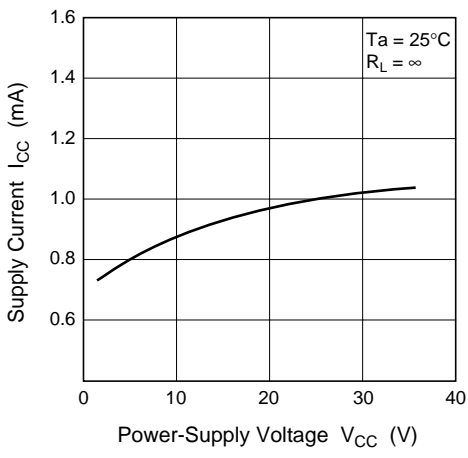
Input Bias Current vs.  
Power-Supply Voltage Characteristics



Supply Current vs.  
Ambient Temperature Characteristics

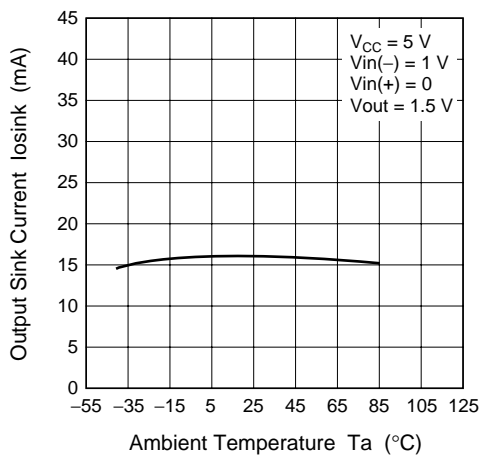


Supply Current vs.  
Power-Supply Voltage Characteristics

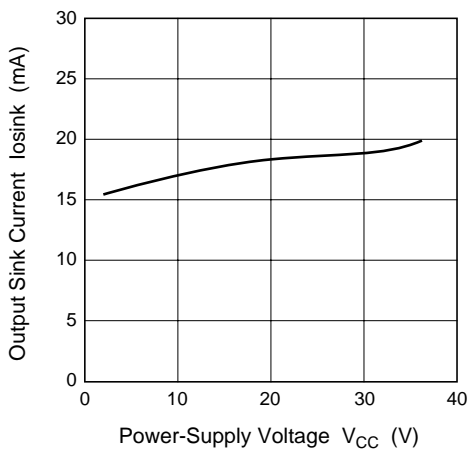




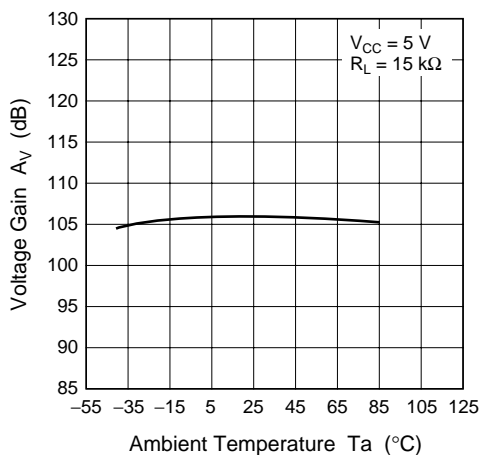
Output Sink Current vs.  
Ambient Temperature Characteristics



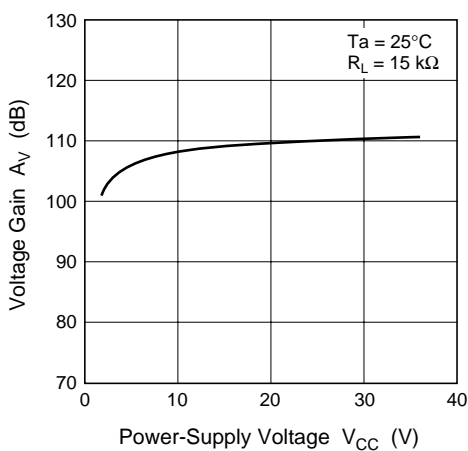
Output Sink Current vs.  
Power-Supply Voltage Characteristics



Voltage Gain vs.  
Ambient Temperature Characteristics



Voltage Gain vs.  
Power-Supply Voltage Characteristics



HA17339/A Application Examples

The HA17339/A houses four independent comparators in a single package, and operates over a wide voltage range at low power from a single-voltage power supply. Since the common-mode input voltage range starts at the ground potential, the HA17339/A is particularly suited for single-voltage power supply applications. This section presents several sample HA17339/A applications.

HA17339/A Application Notes

1. Square-Wave Oscillator

The circuit shown in figure one has the same structure as a single-voltage power supply astable multivibrator. Figure 2 shows the waveforms generated by this circuit.

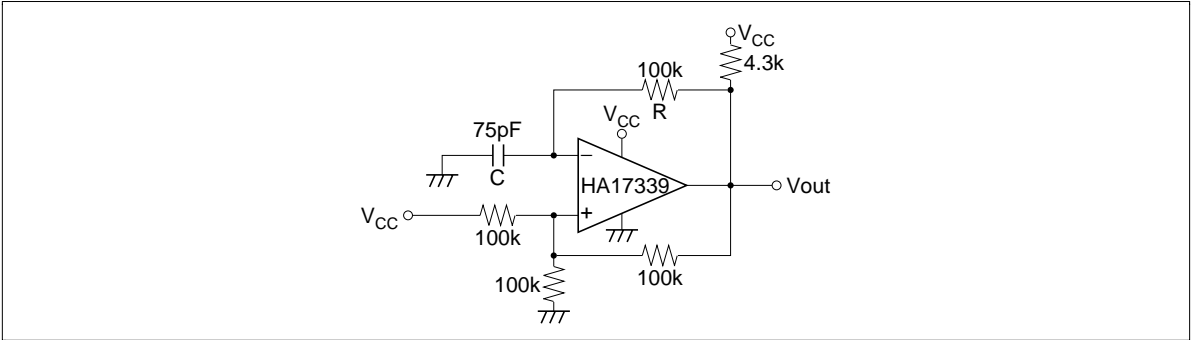


Figure 1 Square-Wave Oscillator

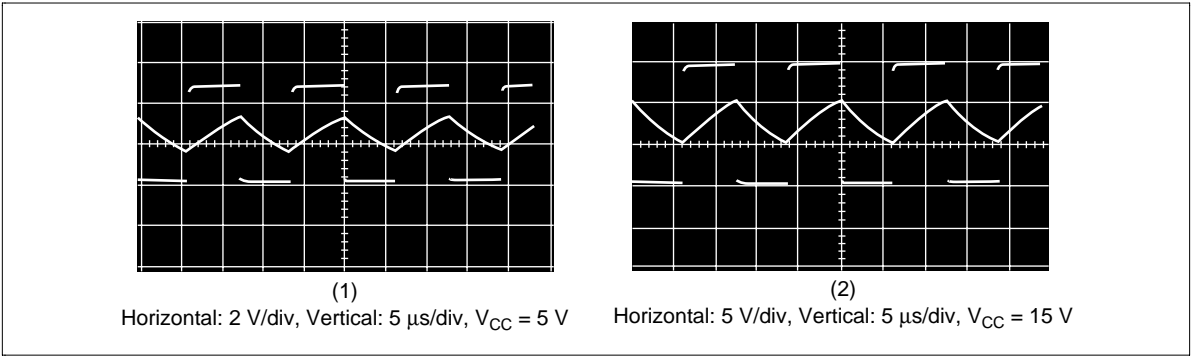


Figure 2 Operating Waveforms

2. Pulse Generator

The charge and discharge circuits in the circuit from figure 1 are separated by diodes in this circuit. (See figure 3.) This allows the pulse width and the duty cycle to be set independently. Figure 4 shows the waveforms generated by this circuit.

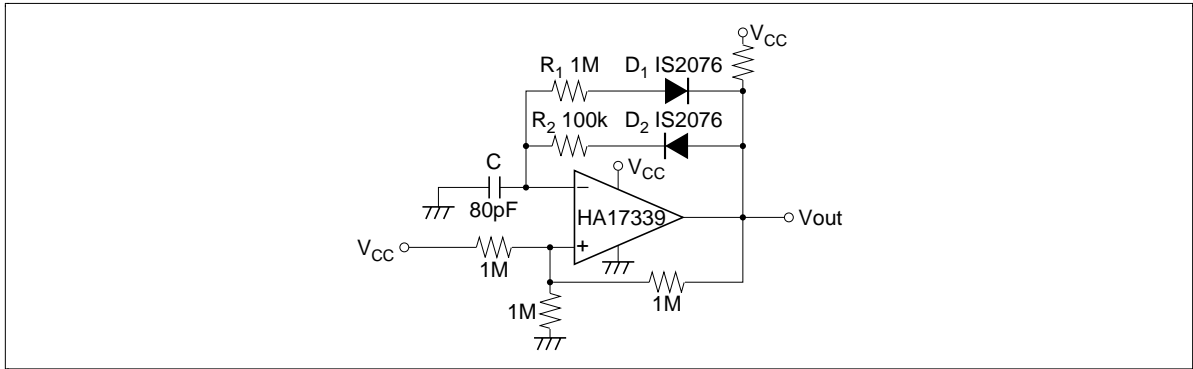


Figure 3 Pulse Generator

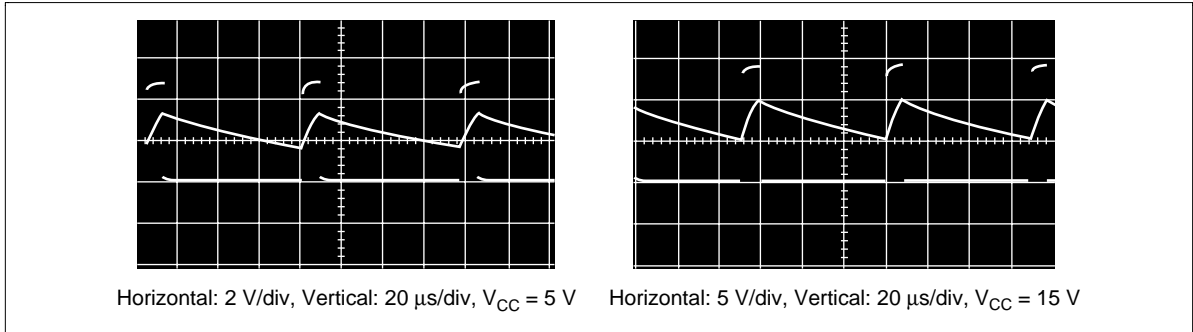


Figure 4 Operating Waveforms

3. Voltage Controlled Oscillator

In the circuit in figure 5, comparator  $A_1$  operates as an integrator,  $A_2$  operates as a comparator with hysteresis, and  $A_3$  operates as the switch that controls the oscillator frequency. If the output  $V_{out1}$  is at the low level, the  $A_3$  output will go to the low level and the  $A_1$  inverting input will become a lower level than the  $A_1$  noninverting input. The  $A_1$  output will integrate this state and its output will increase towards the high level. When the output of the integrator  $A_1$  exceeds the level on the comparator  $A_2$  inverting input,  $A_2$  inverts to the high level and both the output  $V_{out1}$  and the  $A_3$  output go to the high level. This causes the integrator to integrate a negative state, resulting in its output decreasing towards the low level. Then, when the  $A_1$  output level becomes lower than the level on the  $A_2$  noninverting input, the output  $V_{out1}$  is once again inverted to the low level. This operation generates a square wave on  $V_{out1}$  and a triangular wave on  $V_{out2}$ .

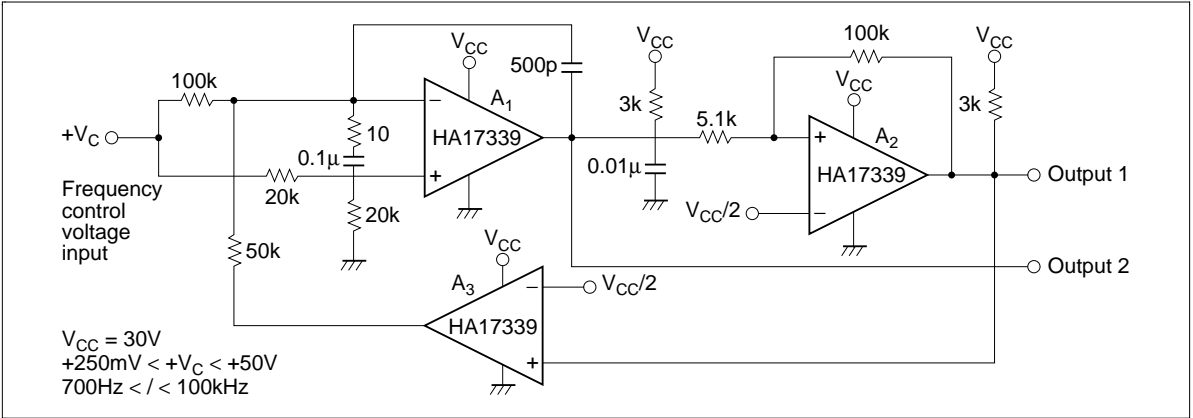


Figure 5 Voltage Controlled Oscillator

4. Basic Comparator

The circuit shown in figure 6 is a basic comparator. When the input voltage  $V_{IN}$  exceeds the reference voltage  $V_{REF}$ , the output goes to the high level.

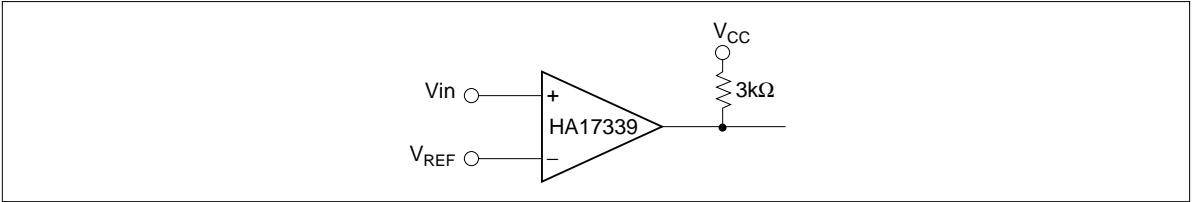


Figure 6 Basic Comparator

5. Noninverting Comparator (with Hysteresis)

Assuming  $+V_{IN}$  is 0V, when  $V_{REF}$  is applied to the inverting input, the output will go to the low level (approximately 0V). If the voltage applied to  $+V_{IN}$  is gradually increased, the output will go high when the value of the noninverting input,  $+V_{IN} \times R_2 / (R_1 + R_2)$ , exceeds  $+V_{REF}$ . Next, if  $+V_{IN}$  is gradually lowered,  $V_{out}$  will be inverted to the low level once again when the value of the noninverting input,  $(V_{out} - V_{IN}) \times R_1 / (R_1 + R_2)$ , becomes lower than  $V_{REF}$ . With the circuit constants shown in figure 7, assuming  $V_{CC} = 15V$  and  $+V_{REF} = 6V$ , the following formula can be derived, i.e.  $+V_{IN} \times 10M / (5.1M + 10M) > 6V$ , and  $V_{out}$  will invert from low to high when  $+V_{IN}$  is  $> 9.06V$ .

$$(V_{out} - V_{IN}) \times \frac{R_1}{R_1 + R_2} + V_{IN} < 6V$$

(Assuming  $V_{out} = 15V$ )

When  $+V_{IN}$  is lowered, the output will invert from high to low when  $+V_{IN} < 1.41V$ . Therefore this circuit has a hysteresis of 7.65V. Figure 8 shows the input characteristics.

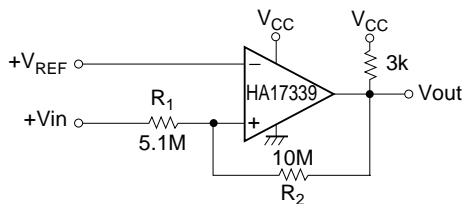


Figure 7 Noninverting Comparator

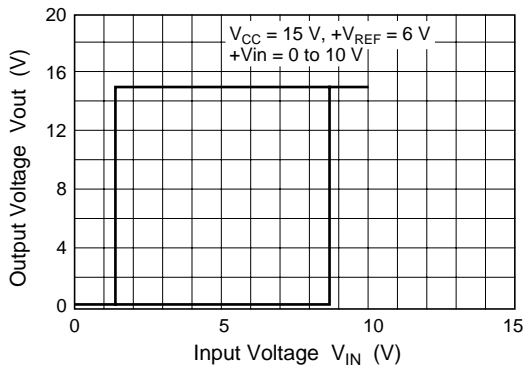


Figure 8 Noninverting Comparator I/O Transfer Characteristics

6. Inverting Comparator (with Hysteresis)

In this circuit, the output  $V_{out}$  inverts from high to low when  $+V_{IN} > (V_{CC} + V_{out})/3$ . Similarly, the output  $V_{out}$  inverts from low to high when  $+V_{IN} < V_{CC}/3$ . With the circuit constants shown in figure 9, assuming  $V_{CC} = 15V$  and  $V_{out} = 15V$ , this circuit will have a 5V hysteresis. Figure 10 shows the I/O characteristics for the circuit in figure 9.

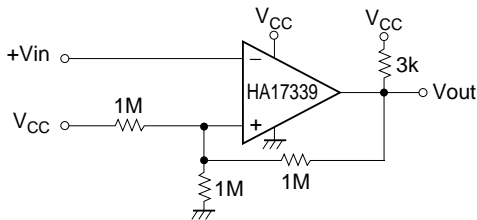


Figure 9 Inverting Comparator

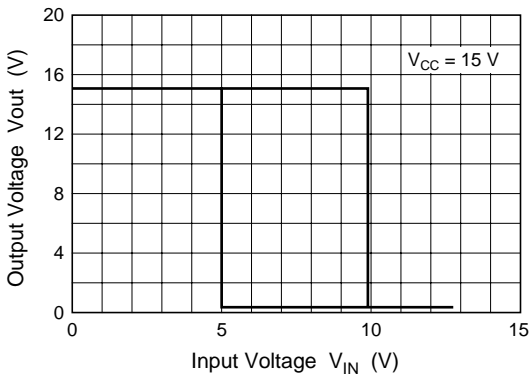


Figure 10 Inverting Comparator I/O Transfer Characteristics

7. Zero-Cross Detector (Single-Voltage Power Supply)

In this circuit, the noninverting input will essentially be held at the potential determined by dividing  $V_{CC}$  with  $100\text{k}\Omega$  and  $10\text{k}\Omega$  resistors. When  $V_{IN}$  is 0V or higher, the output will be low, and when  $V_{IN}$  is negative,  $V_{out}$  will invert to the high level. (See figure 11.)

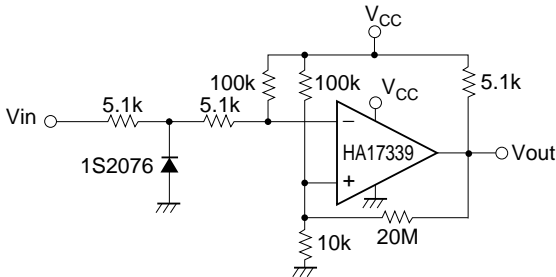
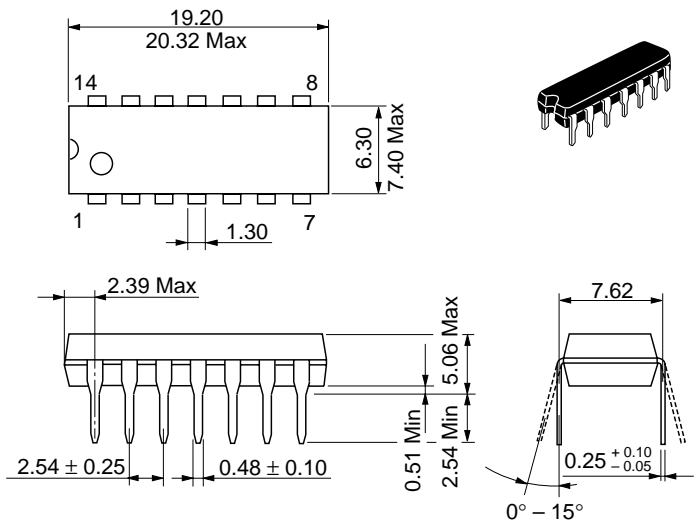


Figure 11 Zero-Cross Detector

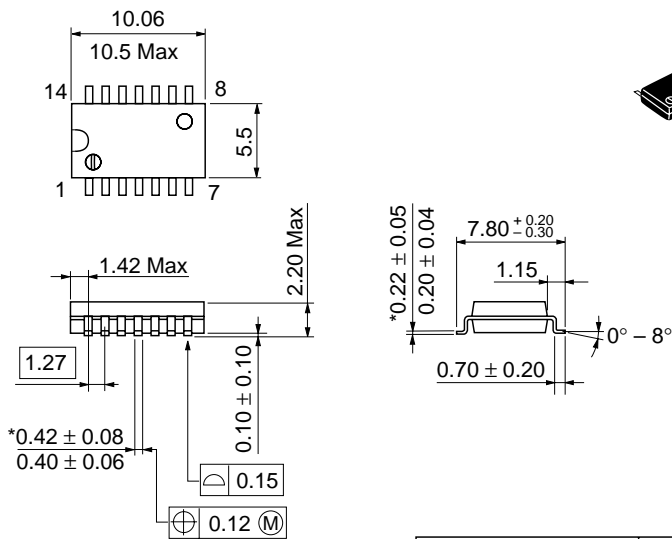
Package Dimensions

Unit: mm



Hitachi Code	DP-14
JEDEC	Conforms
EIAJ	Conforms
Mass (reference value)	0.97 g

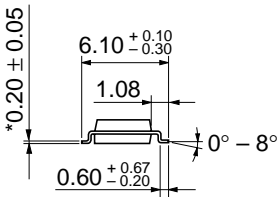
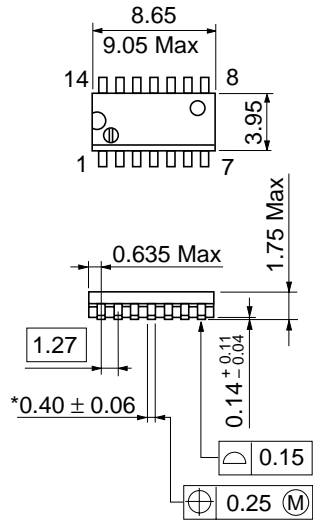
Unit: mm



\*Dimension including the plating thickness  
Base material dimension

Hitachi Code	FP-14DA
JEDEC	—
EIAJ	Conforms
Mass (reference value)	0.23 g

Unit: mm



\*Pd plating

Hitachi Code	FP-14DN
JEDEC	Conforms
EIAJ	Conforms
Mass (reference value)	0.13 g



## Cautions

1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as fail-safes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
5. This product is not designed to be radiation resistant.
6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

# HITACHI

## Hitachi, Ltd.

Semiconductor & Integrated Circuits.  
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan  
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL	NorthAmerica	:	<a href="http://semiconductor.hitachi.com/">http://semiconductor.hitachi.com/</a>
	Europe	:	<a href="http://www.hitachi-eu.com/hel/ecg">http://www.hitachi-eu.com/hel/ecg</a>
	Asia	:	<a href="http://sicapac.hitachi-asia.com">http://sicapac.hitachi-asia.com</a>
	Japan	:	<a href="http://www.hitachi.co.jp/Sicd/indx.htm">http://www.hitachi.co.jp/Sicd/indx.htm</a>

### For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose, CA 95134 Tel: <1> (408) 433-1990 Fax: <1> (408) 433-0223	Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 585200
--------------------------------------------------------------------------------------------------------------------------------------------	-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------

Hitachi Europe GmbH  
Electronic Components Group  
Dornacher Straße 3  
D-85622 Feldkirchen, Munich  
Germany  
Tel: <49> (89) 9 9180-0  
Fax: <49> (89) 9 29 30 00

Hitachi Asia Ltd.  
Hitachi Tower  
16 Collyer Quay #20-00,  
Singapore 049318  
Tel: <65>-538-6533/538-8577  
Fax: <65>-538-6933/538-3877  
URL: <http://www.hitachi.com.sg>

Hitachi Asia Ltd.  
(Taipei Branch Office)  
4/F, No. 167, Tun Hwa North Road,  
Hung-Kuo Building,  
Taipei (105), Taiwan  
Tel: <886>-(2)-2718-3666  
Fax: <886>-(2)-2718-8180  
Telex: 23222 HAS-TP  
URL: <http://www.hitachi.com.tw>

Hitachi Asia (Hong Kong) Ltd.  
Group III (Electronic Components)  
7/F., North Tower,  
World Finance Centre,  
Harbour City, Canton Road  
Tsim Sha Tsui, Kowloon,  
Hong Kong  
Tel: <852>-(2)-735-9218  
Fax: <852>-(2)-730-0281  
URL: <http://semiconductor.hitachi.com.hk>

Copyright © Hitachi, Ltd., 2001. All rights reserved. Printed in Japan.

Colophon 3.0

## HITACHI